

1N4001W

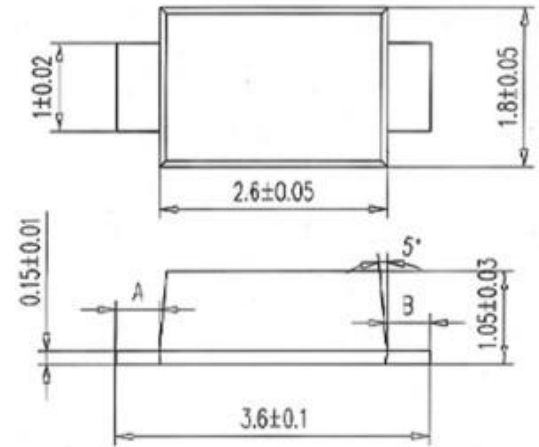
Forward Current - 1 A

FEATURES

- For surface mounted applications
- Low profile package
- Glass Passivated Chip Junction
- Ideal for automated placement
- Lead free in comply with EU RoHS 2011/65/EU directives

MECHANICAL DATA

- Case: SOD-123F
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 14mg



Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	Symbols	1N4001W	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	V
Maximum RMS voltage	V_{RMS}	35	V
Maximum DC Blocking Voltage	V_{DC}	50	V
Maximum Average Forward Rectified Current at $T_c = 125^\circ\text{C}$	$I_{F(AV)}$	1	A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load	I_{FSM}	25	A
Maximum Instantaneous Forward Voltage at 1 A	V_F	1.1	V
Maximum DC Reverse Current $T_a = 25^\circ\text{C}$ at Rated DC Blocking Voltage $T_a = 125^\circ\text{C}$	I_R	5 50	μA
Typical Junction Capacitance ⁽¹⁾	C_j	11	pF
Typical Thermal Resistance ⁽²⁾	$R_{\theta JA}$	90	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_j, T_{stg}	-55 ~ +150	$^\circ\text{C}$

(1) Measured at 1 MHz and applied reverse voltage of 4 V.D.C

(2) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.

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Fig.1 Forward Current Derating Curve

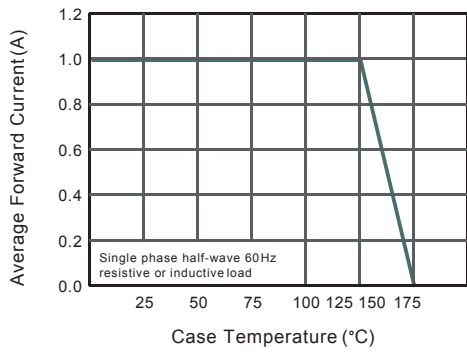


Fig.2 Typical Instaneous Reverse Characteristics

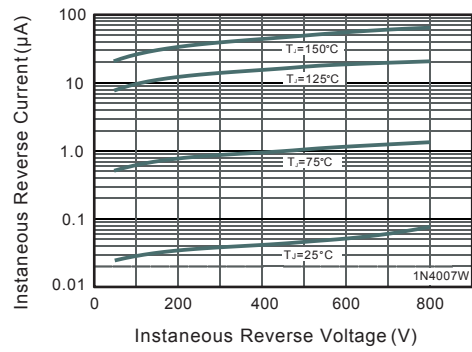


Fig.3 Typical Forward Characteristic

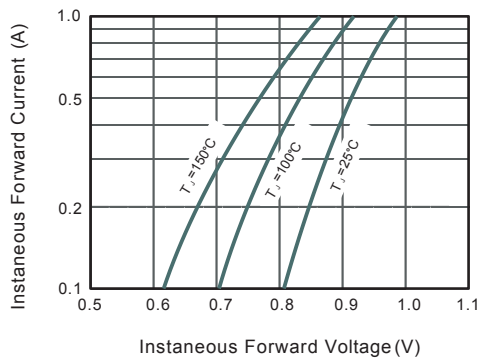


Fig.4 Typical Junction Capacitance

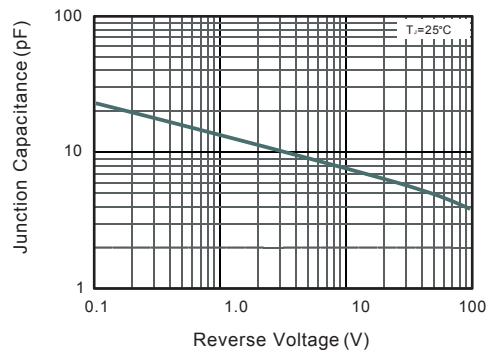


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

